# NSN 5961-01-131-1756

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AeroBase Group

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Inclosure Material:

Metal

**Overall Length:** 

0.300 inches

# **Overall Diameter:**

0.450 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact-darlington connected

#### **Mounting Method:**

Unthreaded hole

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

400.0 collector to emitter voltage, dc with specified circuit between base and emitter

#### **Current Rating Per Characteristic:**

20.00 amperes source cutoff current

## Power Rating Per Characteristic:

175.0 watts small-signal input power, common-collector absolute

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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